

Comment on “Dirac cones reshaped by interaction effects in suspended graphene” by Elias et al., Nature Physics 7, 701 (2011)

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In a recent paper Elias et al.¹ studied the reshaping of the Dirac cone in graphene due to electron-electron interaction using renormalization group theory and compared it to measurements of the velocity $v(n)$ when the carrier concentration $n \rightarrow 0$. The small parameter of expansion was the inverse of the fermion species in graphene $1/N_F$, with $N_F = 4$. The result they found is that the velocity diverges logarithmically as the energy or the density of carriers approaches zero. The velocity becomes then:

$$v(n) = v_F(n_0)[1 + b \ln(n_0/n)], \quad (1)$$

where n_0 is the concentration that corresponds to the ultraviolet cut-off energy and $v_F(n_0)$ is the Fermi velocity near the cut-off. This result is not new and was obtained more than ten years ago^{2,3} and it is not for $N_F = 4$ but for $N_F \rightarrow \infty$. However, it is expected that for $N_F = 4$ it is a good approximation, although when N_F decreases the result is poorer, see Refs. 4 and 5 for this discussion. Son⁵ proposed that $N_F = 2$, one for the spin. Let us now consider that Eq. (1) is a good approximation. Then the dispersion relation is:

$$E(k) = k(1 - a \ln(k)), \quad (2)$$

where a is a constant and k the wavevector measured from the H point of the Brillouin zone. The question that arises now is where are the Dirac carriers? The dispersion relation is not anymore linear. Are there Dirac fermions or not?

Figure 1 shows the dispersion relations for electrons with positive, zero and negative masses. It can be noticed that electrons with a dispersion relation given by Eq. (2) have actually negative mass. In this case they are actually holes for energy larger than zero and the holes for energy smaller than zero should be electrons. Indeed, not a really clear, simple description for the band carriers.

In addition, the bands are difficult to discriminate between Eq. (2) or a law like $k^{1-\alpha}$ that may correspond to small N_F . In Fig. 1 we have plotted this dispersion relation because this is precisely what appears for N_F finite, where $\alpha \simeq 0.15 \dots 0.2$, see Ref. 5. By choosing different parameters it is difficult to conclude, which of the laws, the logarithmic or the power law, is the one that would fit the data. We note that the authors in Ref. 1 insinuate that their data show an excellent agreement with the used model for N_F large. But actually the scattering of the data is rather large and the agreement is poor.

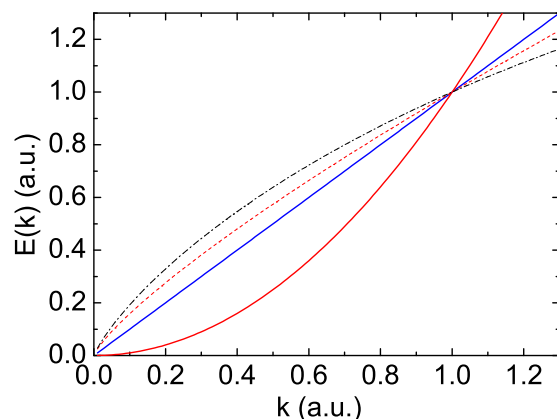


FIG. 1. Dispersion relation $E(k)$ vs. wavevector k for: a quadratic dispersion relation for positive electron mass (read continuous curve) $E(k) = k^2$, a linear dispersion relation $E(k) = k$ for zero electronic mass (straight blue curve), a power law relation $E(k) = k^{0.8}$ (dotted line) as proposed in Ref. 5 and $E(k) = k(1 - 0.4 \ln(k))$ (black dashed-dotted line). Note that the last two dispersion relations imply negative masses for the carriers.

The approximated theory for small N_F predicts that for $N_F < 2.53$ a band gap appears in the excitation spectrum, something that would be difficult to get from the approximations used by the authors in Ref. 1. However, this has been solved later by Drut and Lähde⁶ using Monte Carlo simulations and proved that a band gap appears for the case of ideal graphene and small N_F . The existence of a narrow gap has been recently shown by transport measurements in mesoscopic, thin graphite samples⁷. The existence of an energy gap will solve automatically the apparent difficulties between holes and electrons discussed before and the dispersion at low energies will be rather parabolic or other complicated behavior but not linear.

In conclusion, two different points of view are available to understand the behavior of graphene at low energies. One is considering a large N_F , that makes graphene a semimetal, and another for small $N_F < 2.5$ that would make graphene a narrow gap semiconductor⁵,

a prediction supported independently by Monte Carlo simulations⁶. Taking into account recently obtained ex-

perimental evidence for weakly coupled graphene layers, i.e. graphite⁷, we tend to support the last one.

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